

Surface Mount Attenuator 10 Watts, 5dB



The XRA10AA5SES is a high performance Aluminum Nitride (AIN) chip attenuator intended as a cost competitive alternative to Beryllium Oxide (BeO). It is designed particularly for LTE and 5G wireless communication frequency bands. The high power handling makes the part ideal for interstage matching, directional couplers, and for use in isolators. The attenuator is also RoHS compliant!

General Specifications

Resistive Element	Thick film
Substrate	AIN Ceramic
Terminal Finish	Matte Tin over Nickel Barrier
Operating Temperature	-55 to +150°C (see de rating chart)
Tolerance is ± 0.010 ", unless otherwise specified. Designed to meet or exceed	

applicable portions of MIL-E-5400. All dimensions in inches.

Electrical Specifications

Attenuation Value:	5.0 ± 0.5 dB
Power:	10 Watts
Frequency Range:	DC – 6.0GHz
Input Return Loss:	20dB

Specification based on unit properly installed using suggested mounting instructions and a 50 ohm nominal impedance. **Specifications subject to change.**

<u>Outline</u>

Features:

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RoHS Compliant

10 Watts

Low Cost

Element

Low VSWR

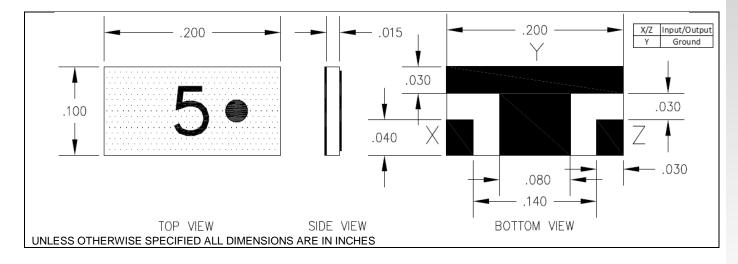
100% Tested

DC - 6.0GHz

AIN Ceramic

Non-Nichrome Resistive

Drawing



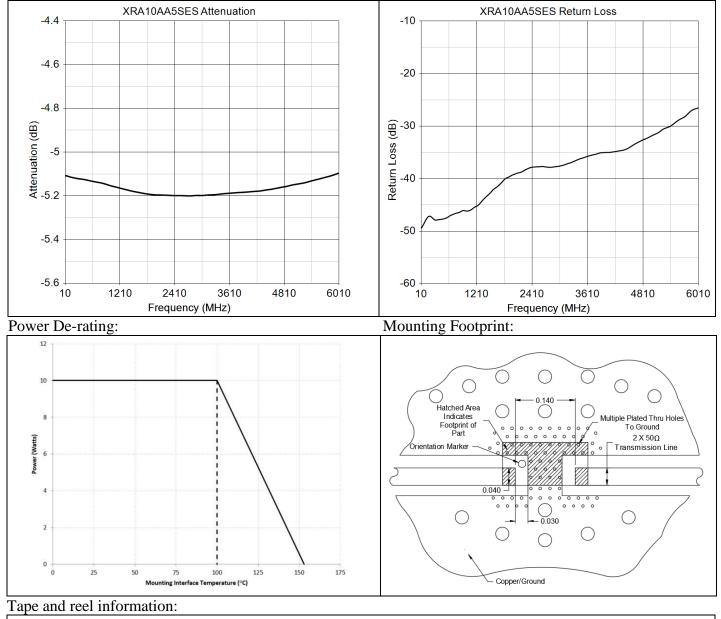


USA/Canada: Toll Free: Europe:

XRA10AA5SES



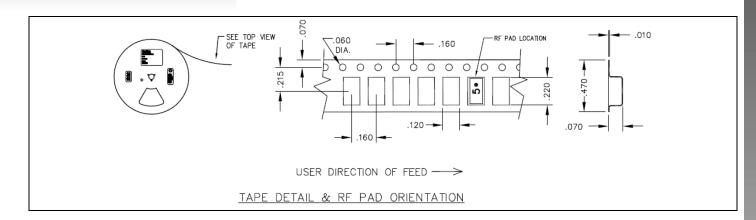
Typical Performance







XRA10AA5SES



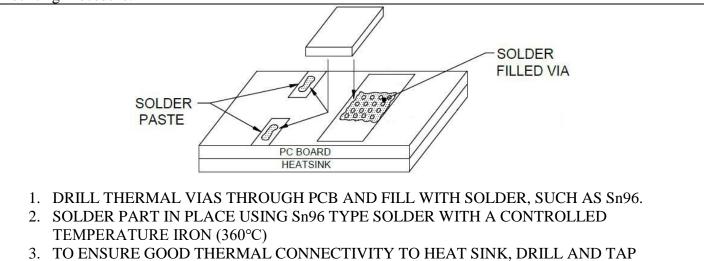


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Mounting Procedure:



3. TO ENSURE GOOD THERMAL CONNECTIVITY TO HEAT SINK, DRILL AND TAP HEATSINK AND MOUNT PCB BOARD TO HEATSINK USING SCREWS WITHIN 1.5" OF PART

> USA/Canada: Toll Free: Europe:

